### 1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection in a DSN0603-2 (SOD962-2) leadless ultra small Chip-Scale Package (CSP).

### 2. Features and benefits

- Average forward current I<sub>F(AV)</sub> ≤ 0.2 A
- Reverse voltage V<sub>R</sub> ≤ 40 V
- Low forward voltage typ. V<sub>F</sub> = 250 mV
- Low reverse current typ. I<sub>R</sub> = 3 μA
- Package height typ. 0.3 mm

## 3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Ultra high speed switching
- LED backlight for mobile application

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5; f = 20 kHz; $T_{amb} \le$ 140 °C; square wave	[1]	-	-	0.2	Α
		$\delta$ = 0.5; f = 20 kHz; $T_{sp} \le$ 147 °C; square wave		-	-	0.2	Α
$V_R$	reverse voltage	T <sub>j</sub> = 25 °C		-	-	40	V
V <sub>F</sub>	forward voltage	$I_F$ = 10 mA; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_j$ = 25 °C		-	250	320	mV
I <sub>R</sub>	reverse current	$V_R = 10 \text{ V}; T_j = 25 \text{ °C}; \text{ pulsed}$		-	3	20	μΑ
t <sub>rr</sub>	reverse recovery time	$I_F$ = 500 mA; $I_R$ = 500 mA; $I_{R(meas)}$ = 100 mA; $T_j$ = 25 °C		-	1.25	-	ns

 $\begin{tabular}{ll} [1] & Device mounted on a ceramic Printed-Circuit Board (PCB), Al_2O_3, standard footprint. \end{tabular}$ 





# 5. Pinning information

#### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]		1 <del>][-]</del> 2
2	Α	anode		sym001
			Transparent top view	
			DSN0603-2 (SOD962-2)	

<sup>[1]</sup> The marking bar indicates the cathode.

# 6. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
PMEG4002AESF	DSN0603-2	Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm	SOD962-2				

# 7. Marking

### Table 4. Marking codes

Type number	Marking code
PMEG4002AESF	N

### 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C		-	40	V
I <sub>F</sub>	forward current	T <sub>sp</sub> ≤ 145 °C; δ = 1		-	0.28	Α
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5; f = 20 kHz; $T_{amb} \le$ 140 °C; square wave	[1]	-	0.2	A
		$\delta$ = 0.5; f = 20 kHz; T <sub>sp</sub> ≤ 147 °C; square wave		-	0.2	A
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ ms}; \ \delta \le 0.25$		-	1.2	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	3.5	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2]	-	405	mW
			[3]	-	660	mW
			[1]	-	1200	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al<sub>2</sub>O<sub>3</sub>, standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm<sup>2</sup> each.

#### 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resista from junction to ambient	thermal resistance		[1][2]	-	-	310	K/W
			[1][3]	-	-	190	K/W
	ambient		[1][4]	-	-	105	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		[5]	-	-	40	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm<sup>2</sup> each.
- [4] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.
- [5] Soldering point of anode tab.

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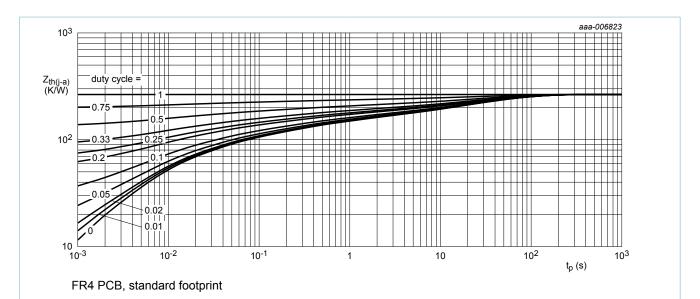


Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

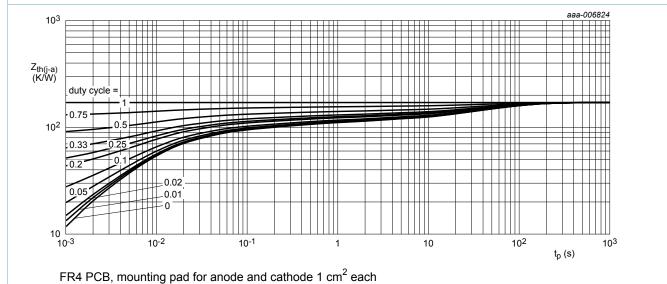
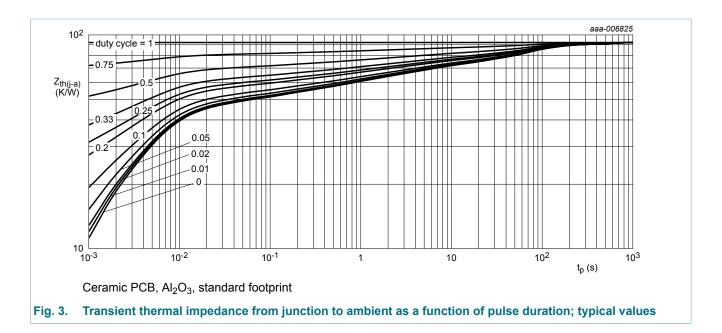


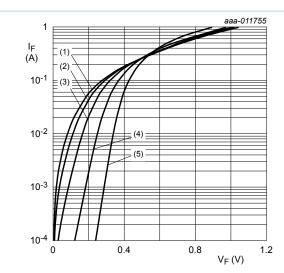
Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)R</sub>	reverse breakdown voltage	$I_R$ = 100 $\mu$ A; $t_p$ = 300 $\mu$ s; $\delta$ = 0.02; $T_{sp}$ = 25 °C	40	-	-	V
V <sub>F</sub>	forward voltage	$I_F$ = 0.1 mA; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_j$ = 25 °C	-	120	185	mV
		$I_F$ = 1 mA; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_j$ = 25 °C	-	180	245	mV
		$I_F$ = 10 mA; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_j$ = 25 °C	-	250	320	mV
		$I_F$ = 100 mA; $t_p \le$ 300 μs; $\overline{o} \le$ 0.02; $T_j$ = 25 °C	-	370	440	mV
		$I_F$ = 200 mA; $t_p$ ≤ 300 μs; $\delta$ ≤ 0.02; $T_j$ = 25 °C	-	450	525	mV
l <sub>R</sub>	reverse current	$V_R = 10 \text{ V}; T_j = 25 ^{\circ}\text{C}; \text{ pulsed}$	-	3	20	μA
		V <sub>R</sub> = 40 V; T <sub>j</sub> = 25 °C; pulsed	-	13	80	μA
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	18	-	pF
		V <sub>R</sub> = 10 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	7	-	pF
t <sub>rr</sub>	reverse recovery time	I <sub>F</sub> = 500 mA; I <sub>R</sub> = 500 mA; I <sub>R(meas)</sub> = 100 mA; T <sub>j</sub> = 25 °C	-	1.25	-	ns



pulsed condition

(1)  $T_i = 150 \, ^{\circ}C$ 

(2)  $T_i = 125 \, ^{\circ}C$ 

(3)  $T_i = 85 \, ^{\circ}C$ 

(4)  $T_j = 25 \, ^{\circ}C$ 

(5)  $T_i = -40 \, ^{\circ}C$ 

Fig. 4. Forward current as a function of forward voltage; typical values

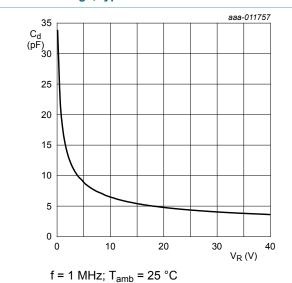
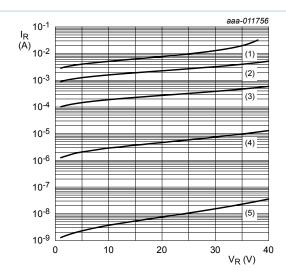


Fig. 6. Diode capacitance as a function of reverse voltage; typical values



pulsed condition

(1)  $T_i = 150 \, ^{\circ}C$ 

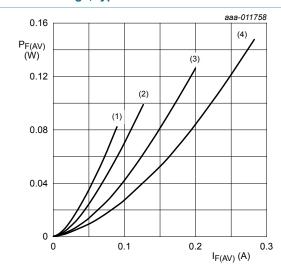
(2)  $T_i = 125 \, ^{\circ}C$ 

(3)  $T_j = 85 \, ^{\circ}C$ 

(4)  $T_i = 25 \, ^{\circ}C$ 

(5)  $T_i = -40 \, ^{\circ}C$ 

Fig. 5. Reverse current as a function of reverse voltage; typical values



 $T_i = 150 \, ^{\circ}C$ 

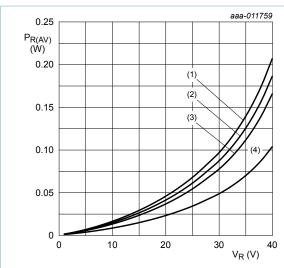
 $(1) \delta = 0.1$ 

 $(2) \delta = 0.2$ 

 $(3) \delta = 0.5$ 

 $(4) \delta = 1$ 

ig. 7. Average forward power dissipation as a function of average forward current; typical values



 $T_i = 125 \,{}^{\circ}\text{C}$ 

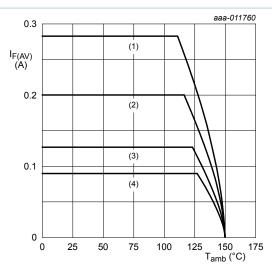
 $(1) \delta = 1$ 

 $(2) \delta = 0.9$ 

 $(3) \delta = 0.8$ 

 $(4) \delta = 0.5$ 

Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

T<sub>i</sub> = 150 °C

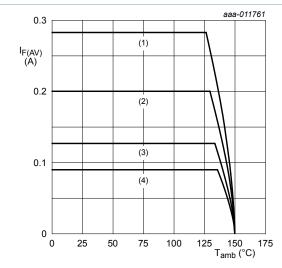
(1)  $\delta$  = 1; DC

(2)  $\delta$  = 0.5; f = 20 kHz

(3)  $\delta$  = 0.2; f = 20 kHz

(4)  $\delta$  = 0.1; f = 20 kHz

Fig. 9. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for anode and cathode

1 cm<sup>2</sup> each

 $T_i = 150 \,{}^{\circ}\text{C}$ 

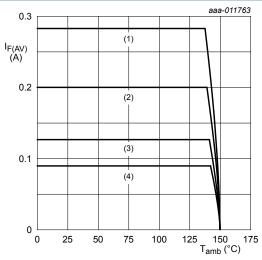
(1)  $\delta$  = 1; DC

(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta$  = 0.1; f = 20 kHz

Fig. 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

 $T_i = 150 \, ^{\circ}C$ 

(1)  $\delta$  = 1; DC

(2)  $\delta$  = 0.5; f = 20 kHz

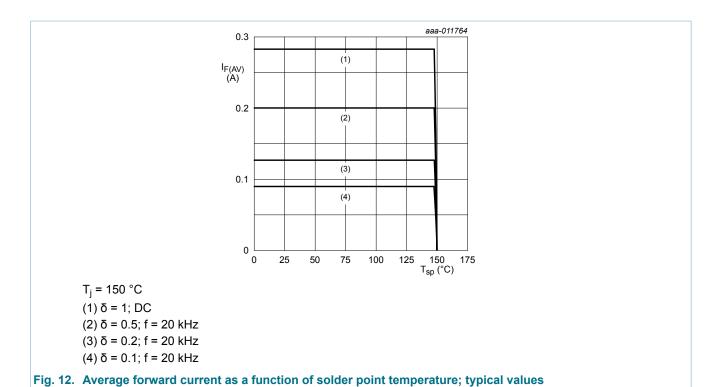
(3)  $\delta$  = 0.2; f = 20 kHz

(4)  $\delta$  = 0.1; f = 20 kHz

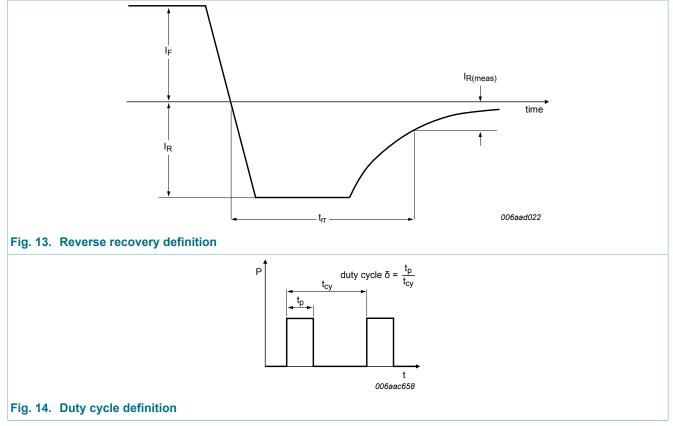
Fig. 11. Average forward current as a function of ambient temperature; typical values

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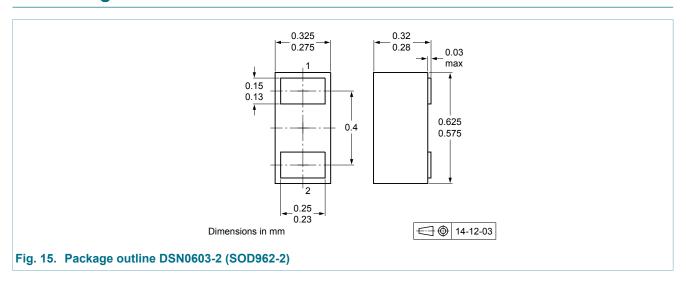


### 11. Test information

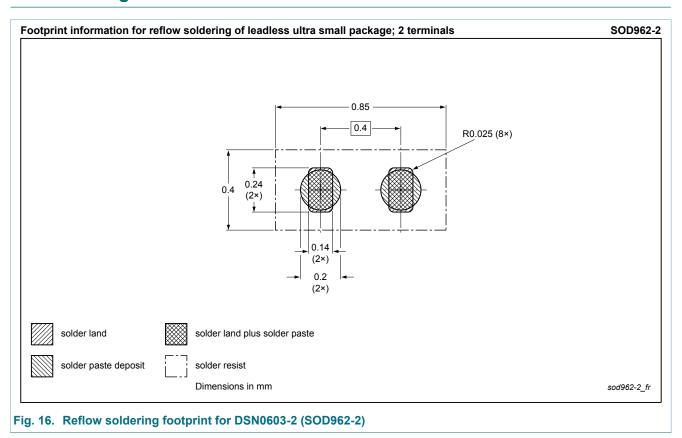


The current ratings for the typical waveforms are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

## 12. Package outline



## 13. Soldering



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# 14. Revision history

#### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMEG4002AESF v.2	20150206	Product data sheet	-	PMEG4002AESF v.1		
Modifications:	Product status changed					
PMEG4002AESF v.1	20140408	Preliminary data sheet	-	-		

### 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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